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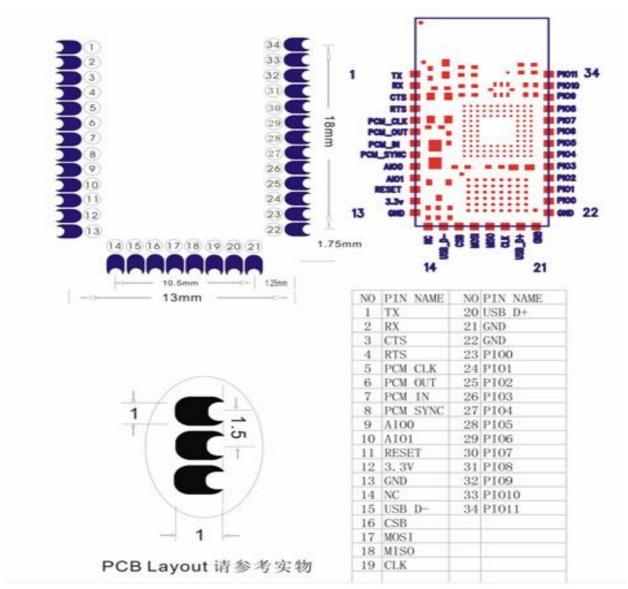






1. Product

Photo





 $27\text{mm} \times 13\text{mm} \times 2\text{mm}$

2 · Feature

z Radio Transceiver

Typical –80dBm sensitivity

Up to +4dBm RF transmit power with power level control

Fully Qualified Bluetooth V2.0+EDR(Enhanced Data Rate) 2Mbps Modulation Integrated 15-bit Linear 8KHz Sample Frequency Audio CODEC in one chip

Internal 6Mbit ROM

Low Power 1.8V Operation

Integrated Switch-Mode Regulator (DC To DC)

Integrated Battery Charger With Programmable Current

PIO control

Standard HCI(UART or USB)

4.2V Tolerant LED Drivers With Intensity Control

UART interface with programmable baud rate

Basic module without antenna

Basic module as SMD type

With Audio Out & Audio in

z Package option

Edge connector

3. Summary of Benefit

z Complete Bluetooth Solution

Complete 2.4GHz radio transceiver and baseband

CSR Bluecore 04-Audio ROM, single chip bluetooth system with CMOS technology

Adaptive frequency hopping feature (AFH)

Smallest footprint, 27mmX13mm

Simplify overall design/development cycle

Full speed Class 2 bluetooth operation

Class I support using external power amplifier

- z Low power standby modes to enable high efficient power management
- z High performance radio transceiver
- z Low overall system cost
- z Application

Mouse

Automotive Hands-Free Kits

Cordless headsets

z Software

Support CSR bluetooth stack

Design for Client

$\mathbf{4}\cdot\mathbf{Device}$ Terminal Function

PIN Name	PIN #	Pad type	Description	Note
	13			
GND	21	VSS	Ground pot	
	22			
			Integrated 3.3V (+) supply with	
3.3	12	3.3V	On-chip linear regulator output	
VCC			within 3.15-3.3V	
AIO0	9	Bi-Directional	Programmable input/output line	
AIO1	10	Bi-Directional	Programmable input/output line	
DIOO	22	Bi-Directional	Programmable input/output line,	
PIO0	23	RX EN	control output for LNA(if fitted)	
PIO1	24	Bi-Directional	Programmable input/output line,	
FIOI	24	TX EN	control output for PA(if fitted)	
PIO2	25	Bi-Directional	Programmable input/output line	
PIO3	26	Bi-Directional	Programmable input/output line	
PIO4	27	Bi-Directional	Programmable input/output line	
PIO5	28	Bi-Directional	Programmable input/output line	
PIO6	29	Bi-Directional	Programmable input/output line	
PIO7	30	Bi-Directional	Programmable input/output line	
PIO8	31	Bi-Directional	Programmable input/output line	
PIO9	32	Bi-Directional	Programmable input/output line	
PIO10	33	Bi-Directional	Programmable input/output line	
PIO11	34	Bi-Directional	Programmable input/output line	
RESETB	11			
		CMOS output,		
HADT DTC	4	tri-stable with	LIADT magnest to soul active land	
UART_RTS	4	weak internal	UART request to send, active low	
		pull-up		
		CMOS input with		
UART_CTS	3	weak internal	UART clear to send, active low	
		pull-down		

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	I			
UART_RX	2	CMOS input with weak internal pull-down	UART Data input	
UART_TX	1	CMOS output, Tri-stable with weak internal pull-up	UART Data output	
SPI_MOSI	17	CMOS input with weak internal pull-down	Serial peripheral interface data input	
SPI_CSB	16	CMOS input with weak internal pull-up	Chip select for serial peripheral interface, active low	
SPI_CLK	19	CMOS input with weak internal pull-down	Serial peripheral interface clock	
SPI_MISO	18	CMOS input with weak internal pull-down	Serial peripheral interface data Output	
USB	15	Bi-Directional		
USB_+	20	Bi-Directional		
1.8V	14		Output Dc1.8v	
PCM_CLK	5	Bi-Directional	Synchronous PCM data clock	
PCM_OUT	6	CMOS output	Synchronous PCM data output	
PCM_IN	7	CMOS Input	Synchronous PCM data input	
PCM_SYNC	8	Bi-Directional	Synchronous PCM data strobe	

5. Electrical Specification:

z Eecommended Operating condition

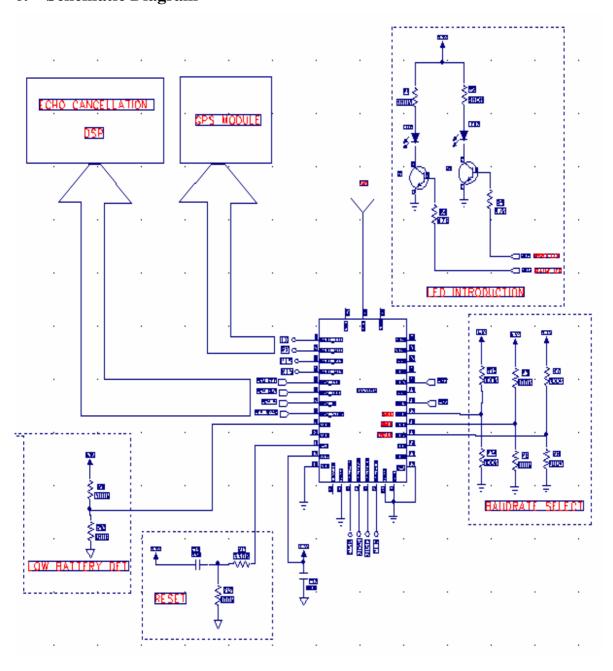
Radio Characteristics	VDD = 1.8V		Temperatur	e = +20°C		
	Min	Тур	Max	Bluetooth Specification	Unit	
Maximum RF transmit power(a) (b)	-	2.5	-	-6 to +4(c)	dBm	
RF power variation over temperature range with compensation enabled(±) ^(d)	-	1.5		-	dB	
RF power variation over temperature range with compensation disabled(±)	-	2			dB	
RF power control range	-	35		≥16	dB	
RF power range control resolution ^(e)	-	0.5			dB	
20dB bandwidth for modulated carrier		780		≤1000	kHz	
Adjacent channel transmit power F = F ₀ ± 2MHz(f) (g)	-	-40		≤-20	dBm	
Adjacent channel transmit power F = F ₀ ± 3MHz		-45		≤-40	dBm	
Adjacent channel transmit power F = F ₀ ± > 3MHz		-50		≤-40	dBm	
∆f1 _{avg} Maximum Modulation	-	165	-	140 <f1<sub>avg<175</f1<sub>	kHz	
Δf2 _{max} Minimum Modulation	-	150		≥115	kHz	
Δf1 _{avg} /Δf2 _{avg}	-	0.97		≥0.80		
Initial carrier frequency tolerance	-	6		±75	kHz	
Drift Rate	-	8	-	≤20	kHz/50μs	
Drift (single slot packet)	-	7	-	≤25	kHz	
Drift (five slot packet)	-	9	-	≤40	kHz	
2 nd Harmonic Content	-	-65	-	≤-30	dBm	
3 rd Harmonic Content	-	-45	-	≤-30	dBm	

z Transmitter

Radio Characteristics	VDD = 1.8V		Temperatur	e = +20°C	
	Min	Тур	Max	Bluetooth Specification	Unit
Maximum RF transmit power ^{(a) (b)}	-	2.5	-	-6 to +4(c)	dBm
RF power variation over temperature range with compensation enabled(±) ^(d)	-	1.5			dB
RF power variation over temperature range with compensation disabled(±)	-	2			dB
RF power control range	-	35		≥16	dB
RF power range control resolution ^(e)	-	0.5			dB
20dB bandwidth for modulated carrier	-	780		≤1000	kHz
Adjacent channel transmit power $F = F_0 \pm 2MHz(f)(g)$		-40		≤-20	dBm
Adjacent channel transmit power $F = F_0 \pm 3 \text{MHz}$		-45		≤-40	dBm
Adjacent channel transmit power $F = F_0 \pm > 3MHz$		-50		≤-40	dBm
∆f1 _{avg} Maximum Modulation	-	165	-	140 <f1<sub>avg<175</f1<sub>	kHz
$\Delta f2_{\text{max}}$ Minimum Modulation	-	150	-	≥115	kHz
$\Delta f1_{avg}/\Delta f2_{avg}$	-	0.97		≥0.80	
Initial carrier frequency tolerance	-	6		±75	kHz
Drift Rate	-	8		≤20	kHz/50μs
Drift (single slot packet)	-	7		≤25	kHz
Drift (five slot packet)	-	9		≤40	kHz
2 nd Harmonic Content	-	-65	-	≤-30	dBm
3 rd Harmonic Content	-	-45	-	≤-30	dBm

Radio Characteristics		VDD = 1.8V	1	Temperatur	e = +20°C	
	Frequency (GHz)	Mn	Тур	Max	Bluetooth Specification	Unit
Sensitivity at 0.1% BER for all packet types	2.402	- 23	-84	%	≤-70	
	2.441		-84	85		dBm
	2.480	- 5	-85	100		
Maximum received signal at 0.1% BER			10	75	≤-20	dBm
	Frequency (MHz)	Mn	Тур	Max	Bluetooth Specification	Unit
Continuous power	30-2000	- 2	-6	%	≤-10	
required to block Bluetooth reception (for	2000-2400	- 5	0	8.5	s-27	1
input power of -67dBm with 0.1% BER) measured at the unbalanced port of the balun.	2500-3000	120	0		s-27	₫Bm
C/I co-channel			6	32	s 11	dB
Adjacent channel selectivity C/I $F = F_0 + \frac{1}{2} M Hz^{(a)} (b)$		ž.	-5	33	s0	dB
Adjacent channel selectivity C/I F = F ₀ - 1MHz		8	-4	85	s0	dB
Adjacent channel selectivity C/I F = F ₀ + 2MHz			-38	185	s-30	dB
Adjacent channel selectivity C/I F = F ₀ - 2MHz		8	-23	14	s-20	dB
Adjacent channel selectivity C/I $F = F_0 + 3MHz$		ž.	-45	32	≤-40	dB
Adjacent channel selectivity C/I F = F ₀ -5MHz		8	-44	85	s-40	dB
Adjacent channel selectivity C/I F = F _{Image}			-22	*	≤-9	dB
Maximum level of intermodulation interferers(c)		5	-30	10	≥-39	dBm
Spurious output level(4)			-150	1 12	2	dBm/H

6. Schematic Diagram



7. Block Diagram

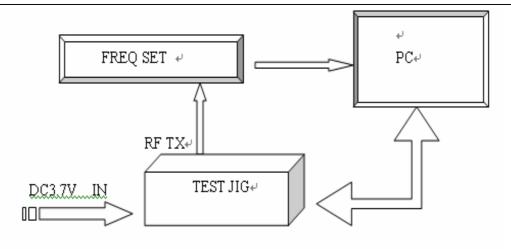


Fig 1 Programming and Freq. Alignment Test Procedure

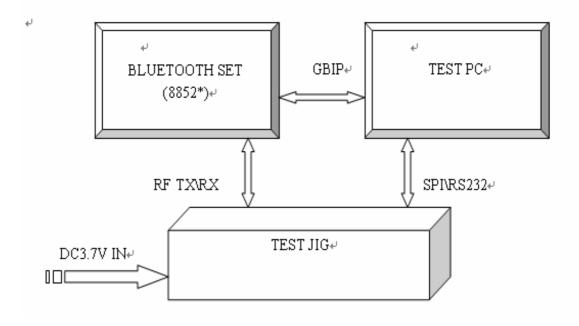


Fig 2 RF Parameter Test procedure

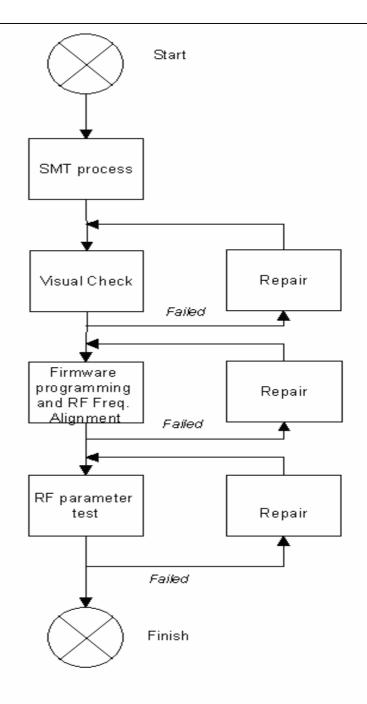


Fig 3 Assemble/Alignment/Testing Flow Chart